

## Features

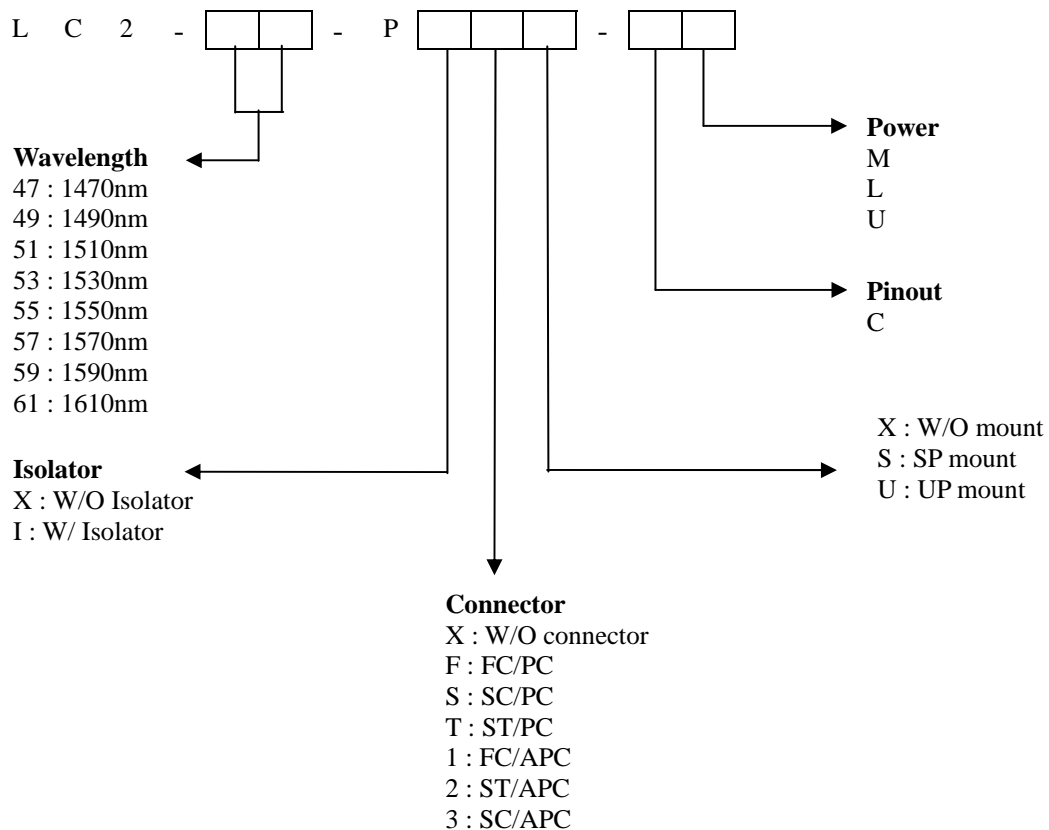


- InGaAsP MQW-DFB laser diode (LD)
- Built-in InGaAs monitor PIN photodiode (PD)
- Uncooled, hermetically sealed
- Low threshold current
- Fiber pigtail type with optional FC/SC/ST connector
- With optional isolator

## Applications

- ATM/SONET OC-48

## Ordering Information





# CWDM 2.5Gbps DFB Laser Diode Pigtail type Module

## Specifications

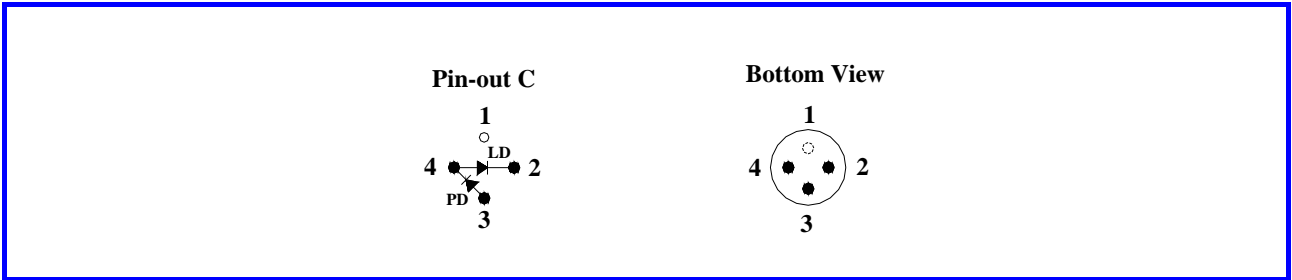
### Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Storage temperature	$T_{stg}$	-40~+85	°C
Operating case temperature	$T_{op}$	0~+70	°C
Peak optical output power	M	1.5	mW
	L	3.0	
	U	4.0	
Reverse voltage (LD)	$V_{RL}$	2	V
Forward current (PD)	$I_{FP}$	2	mA
Reverse voltage (PD)	$V_{RP}$	15	V
Soldering temperature (10 sec.)	$S_{temp}$	260	°C

### Electrical and Optical Characteristics ( $T_C=25^\circ\text{C}$ , unless otherwise specified)

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit	
Threshold current	$I_{th}$	CW	-	10	20	mA	
Center Wavelength	$\lambda_c$	$P_f$	$\lambda_c-3$	-	$\lambda_c+3$	nm	
Fiber output power	M	CW, $I_{th}+25\text{mA}$	0.5	-	1.0	mW	
	L		$P_f$	1.0	-		1.75
	U			2.0	-		-
Slope efficiency	M	CW	0.02	-	0.04	mW/mA	
	L		$Se$	0.04	-		0.07
	U			0.07	-		-
Operating voltage	$V_{op}$	$P_f$	-	-	1.7	V	
Side mode suppression ratio	SMSR	CW, $0^\circ\text{C}\sim+70^\circ\text{C}$	30	-	-	dB	
Rise time	$T_r$	$I_b = I_{th}, 20\%\sim 80\%, 0^\circ\text{C}\sim+70^\circ\text{C}$	-	-	0.25	nsec	
Fall time	$T_f$	$I_b = I_{th}, 80\%\sim 20\%, 0^\circ\text{C}\sim+70^\circ\text{C}$	-	-	0.3	nsec	
Tracking error	$\Delta P_f / P_f$	APC, $0^\circ\text{C}\sim+70^\circ\text{C}$	-	$\pm 1.0$	-	dB	
Monitor current	$I_m$	$P_f$	50	-	-	$\mu\text{A}$	
Monitor dark current	$I_d$	$V_{RP} = 5\text{V}$	-	-	0.01	$\mu\text{A}$	
Monitor capacitance	C	$V_{RP} = 5\text{V}, f=1\text{MHz}$	-	-	10	pF	

## Pin Assignment



## Package Outline Drawing

